TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSVI)

TPC8126

Lithium Ion Battery Applications Power Management Switch Applications

• Small footprint due to small and thin package

• Low drain-source ON-resistance: R_{DS} (ON) = 7.5 m Ω (typ.)

• Low leakage current: $I_{DSS} = -10 \mu A \text{ (max) (V}_{DS} = -30 \text{ V)}$

• Enhancement mode: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_{D} = -0.5mA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteri | stics | Symbol | Rating | Unit | |
|------------------------|---------------------------|------------------|------------|------|--|
| Drain-source voltage | | V_{DSS} | -30 | V | |
| Drain-gate voltage (Ro | _{SS} = 20 kΩ) | V_{DGR} | -30 | V | |
| Gate-source voltage | | V _{GSS} | -25/+20 | V | |
| Drain current | DC (Note 1) | ΙD | -11 | Α | |
| | Pulse (Note 1) | I_{DP} | -44 | A | |
| Drain power dissipatio | n (t = 10 s) (Note 2a) | P_{D} | 1.9 | W | |
| Drain power dissipatio | n (t = 10 s) (Note 2b) | P _D | 1.0 | W | |
| Single pulse avalanch | e energy (Note 3) | E _{AS} | 79 | mJ | |
| Avalanche current | (Note 1) | I _{AR} | -11 | Α | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature r | ange | T _{stg} | -55 to 150 | °C | |

Note 1, Note 2, Note 3: See the next page.

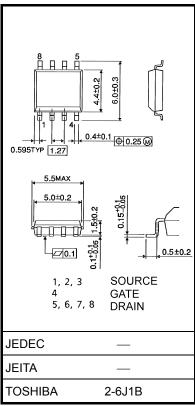
report and estimated failure rate, etc).

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test

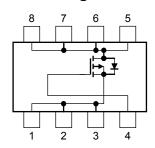
This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm



Weight: 0.080 g (typ.)

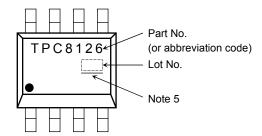
Circuit Configuration



Thermal Characteristics

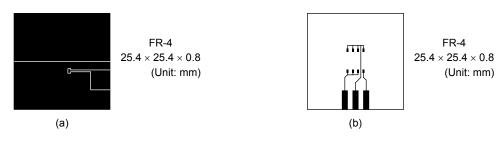
| Characteristics | Symbol | Max | Unit |
|---|------------------------|------|------|
| Thermal resistance, channel to ambient (t = 10 s) (Note 2a) | R _{th (ch-a)} | 65.8 | °C/W |
| Thermal resistance, channel to ambient (t = 10 s) (Note 2b) | R _{th (ch-a)} | 125 | °C/W |

Marking (Note 4)



Note 1: Ensure that the channel temperature does not exceed 150°C.

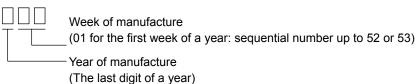
Note 2: (a)Device mounted on a glass-epoxy board (a) (b)Device mounted on a glass-epoxy board (b)



Note 3: $V_{DD} = -24$ V, $T_{ch} = 25$ °C (initial), L = 500 μH , $R_G = 25$ Ω , $I_{AR} = -11$ A

Note 4: • on lower left of the marking indicates Pin 1.

Weekly code: (Three digits)



Note 5: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

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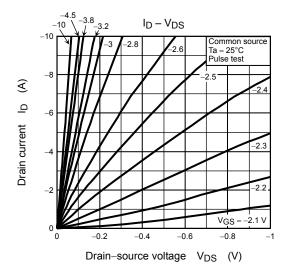
Electrical Characteristics (Ta = 25°C)

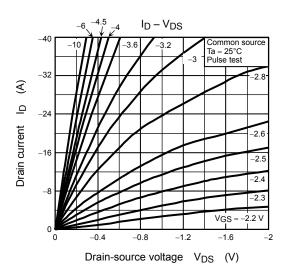
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|---------------------|-----------------------|---|--------|------|------|------|
| Gate leakage curre | ent | I _{GSS} | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$ | — ±100 | | nA | |
| Drain cut-OFF curr | ain cut-OFF current | | $V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$ | _ | _ | -10 | μА |
| Drain-source breakdown voltage | | V _{(BR) DSS} | $I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$ | -30 | _ | _ | V |
| | | V _{(BR) DSX} | $I_D = -10 \text{ mA}, V_{GS} = 10 \text{ V}$ (Note 6) | -21 | _ | _ | |
| Gate threshold vol | tage | V _{th} | $V_{DS} = -10 \text{ V}, I_D = -0.5 \text{ mA}$ | -0.8 | _ | -2.0 | V |
| Drain-source ON-resistance | | D= 0 (01) | $V_{GS} = -4.5 \text{ V}, I_D = -5.5 \text{ A}$ | _ | 10.5 | 14 | - mΩ |
| | | R _{DS} (ON) | $V_{GS} = -10 \text{ V}, I_D = -5.5 \text{ A}$ | _ | 7.5 | 10 | |
| Input capacitance | | C _{iss} | V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz | _ | 2400 | _ | pF |
| Reverse transfer capacitance | | C _{rss} | | _ | 400 | _ | |
| Output capacitance | | C _{oss} | | _ | 460 | _ | |
| Switching time | Rise time | t _r | V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz V _{GS} -10 V D = -5.5A O V OUT G C W C C C C C C C C | _ | 8 | _ | - ns |
| | Turn-ON time | t _{on} | -10 V G S S | _ | 16 | _ | |
| | Fall time | t _f | | _ | 65 | _ | |
| | Turn-OFF time | t _{off} | $V_{DD} \approx -15 \text{ V}$ Duty ≤ 1%, $t_W = 10 \text{ μs}$ | _ | 200 | _ | |
| Total gate charge (gate-source plus gate-drain) | | Qg | V _{DD} ≈ -24 V, V _{GS} = -10 V, | _ | 56 | _ | nC |
| Gate-source charge 1 | | Q _{gs1} | $I_D = -11 \text{ A}$ | _ | 5.6 | _ | |
| Gate-drain ("miller") charge | | Q _{gd} | | _ | 15 | _ | |

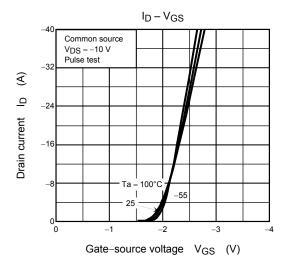
Source-Drain Ratings and Characteristics (Ta = 25°C)

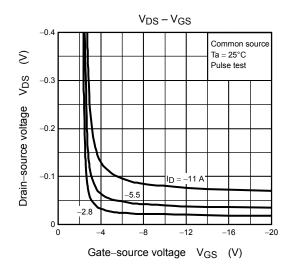
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit | |
|-------------------------|-------|------------------|--|-----|------|-----|------|---|
| Drain reverse current | Pulse | (Note 1) | I _{DRP} | _ | _ | _ | -44 | Α |
| Forward voltage (diode) | | V _{DSF} | I _{DR} = -11 A, V _{GS} = 0 V | _ | _ | 1.2 | V | |

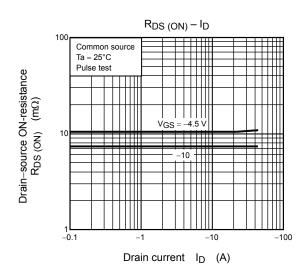
Note 6: VDSX mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.



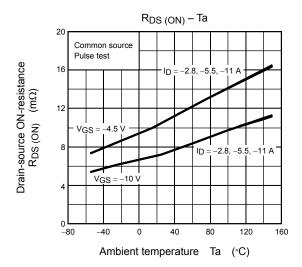


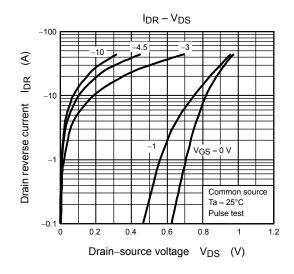


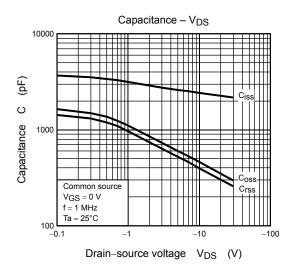


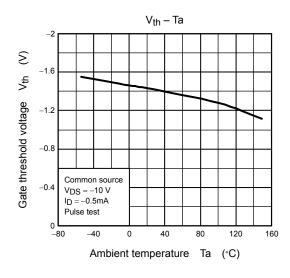


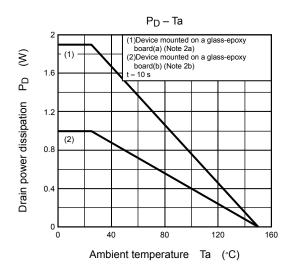
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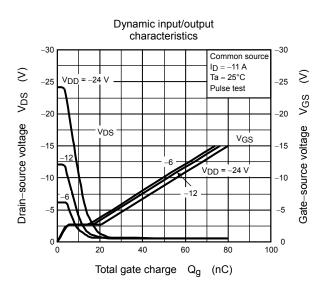


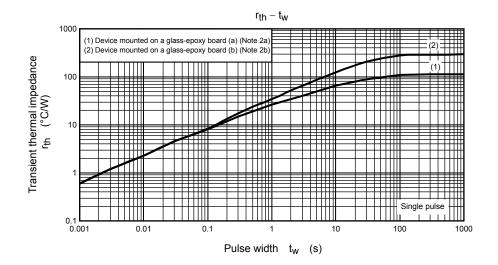


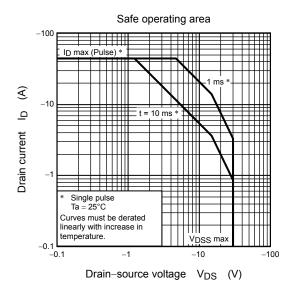












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